

03560.002157.1



PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)
MASAFUMI SANO ET AL.) : Examiner: NYA
Application No.: 10/046,903) : Group Art Unit: 1741
Filed: January 17, 2002) :
For: METHOD OF PRODUCING ZINC)
OXIDE THIN FILM, METHOD OF)
PRODUCING PHOTOVOLTAIC)
DEVICE AND METHOD OF)
PRODUCING SEMICONDUCTOR)
DEVICE) : May 21, 2002

Office of Initial Patent Examination
Customer Service Center
Commissioner for Patents
Washington, D.C. 20231

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REQUEST FOR CORRECTED FILING RECEIPT

Sir:

Applicants' attorneys have received an official Filing Receipt in the above-identified application wherein an error has been noted. The Title is incorrect and should read:

- -Method of producing zinc oxide **thin film**, method of producing **photovoltaic** device
and method of producing semiconductor device- -.

A copy of the official Filing Receipt is attached with the proposed changes marked in red. Issuance of a Corrected Filing Receipt with the correct data is accordingly respectfully requested.

Applicants' undersigned attorney may be reached in our New York office by telephone at (212) 218-2100. All correspondence should continue to be directed to our address given below.

Respectfully submitted,



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UNITED STATES PATENT AND TRADEMARK OFFICE

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APPLICATION NUMBER	FILING DATE	GRP ART UNIT	*FIL FEE REC'D	ATTY.DOCKET.NO	DRAWINGS	TOT CLAIMS	IND CLAIMS
10/046,903	01/17/2002	1741	2396	03560.002157 D1	13	42	18

5514
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NAS
03560.002157.01 CONFIRMATION NO. 3549

FILING RECEIPT



OC000000007498030

Date Mailed: 02/20/2002

Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Customer Service Center. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

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Yuichi Sonoda, Nara-shi, JAPAN;

Domestic Priority data as claimed by applicant

THIS APPLICATION IS A DIV OF 09/074,699 05/08/1998 PAT 6,346,184 *

(*) Data inconsistent with PTO records.

Foreign Applications

JAPAN 1997-121921 05/13/1997

If Required, Foreign Filing License Granted 02/19/2002

Projected Publication Date: 05/30/2002

Non-Publication Request: No

Early Publication Request: No

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Title

thin film, *photovoltaic*
Method of producing zinc oxide thin film method of producing photovoltaic device and method of
producing semiconductor device

Preliminary Class

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Title 35, United States Code, Section 184
Title 37, Code of Federal Regulations, 5.11 & 5.15**

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